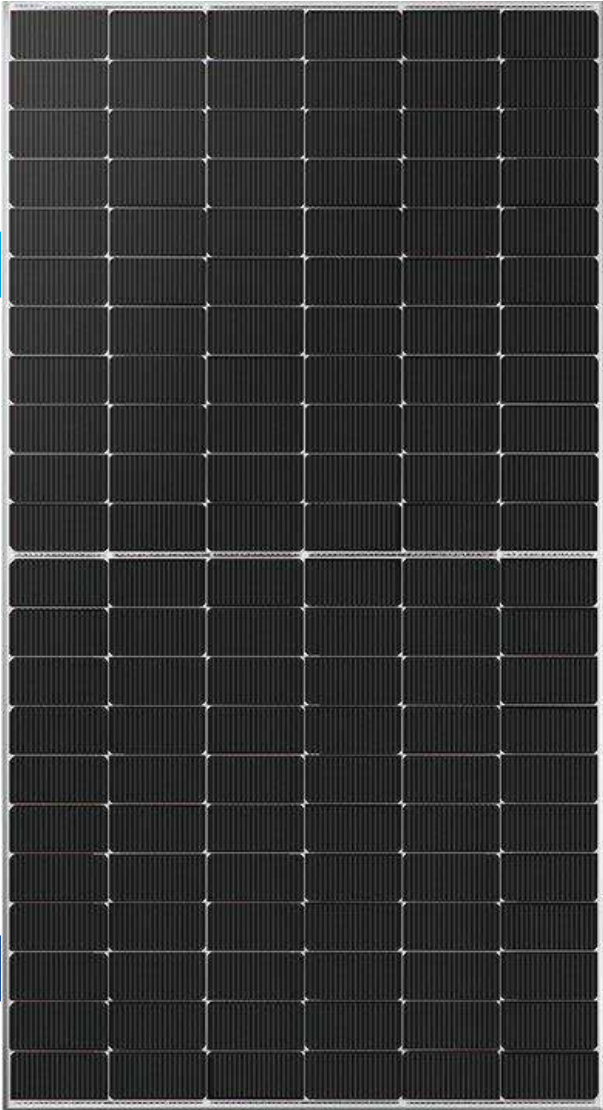


AVN66G12RTB | N-type Bifacial - Transparent Backsheet | 132 Cells | 630 Watt | > 23.30% Efficiency



## "N" TOPCON TECHNOLOGY

610 - 630 WATT



### Up to 30% Additional Power Generation Gain

Additional power gain from rear side depending on albedo



### LOW LID (Light Induced Degradation)

TOPCon cells have low LID, because of its N-Type silicon substrate



### Lower LCOE

High bifaciality, high power output, saving BOS cost



### Better Weak Illumination Response

Wide spectral response, higher power output even under low-light settings like smog or cloudy days



### Better Temperature Coefficient

TOPCon cell has a better temperature coefficient which help in better performance in hot climate



### Wider Applicability

Vertical installation, snowfield, high-humid area

630 W  
MAXIMUM  
POWER OUTPUT

0~+5 W  
POWER OUTPUT  
TOLERANCE

16 BB  
MULTI  
BUSBAR

### Key Features

- ⦿ Fully automatic facility with cutting-edge technology
- ⦿ Guaranteed positive tolerance to ensure power output reliability
- ⦿ Split junction boxes reduce module temperature resulting increased module reliability

### Quality & Reliability

- ⦿ IP68 rated junction box for long-term weather endurance
- ⦿ Made with high-graded raw material to achieve Quality, Durability, Efficiency, and through output
- ⦿ 12 Years Workmanship & 30 Years Linear Performance Warranty

*Disclaimer: As part of continuous innovation and R&D improvements, the specifications and key features outlined in this datasheet may be subject to minor changes and are not guaranteed. Avaada Electro Pvt. Ltd. reserves the right to update the information provided at any time without prior notice. To ensure accuracy, please always refer to the latest version of the datasheet, which will be considered a part of the binding contract governing all transactions related to the purchase and sale of the products described herein.*

